

PJQ2568A

60V N-Channel Enhancement Mode MOSFET

Voltage

60 V

Current

17 A

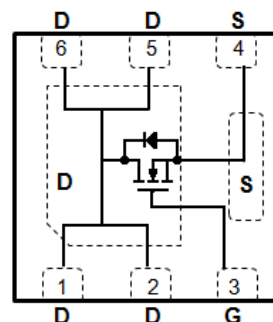
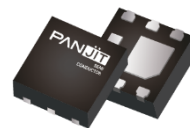
Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@10A<16m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@6A<28m\Omega$
- Excellent FOM
- Logic Level Drive
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN2020B-6L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0086 grams

DFN2020B-6L



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	60	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current ^(Note 3)	$T_C=25^{\circ}C$	I_D	17	A
	$T_C=100^{\circ}C$		11	
Pulsed Drain Current ^(Note 1)	$T_C=25^{\circ}C$	I_{DM}	68	
Power Dissipation	$T_C=25^{\circ}C$	P_D	9.6	W
	$T_C=100^{\circ}C$		3.8	
Continuous Drain Current ^(Note 4)	$T_A=25^{\circ}C$	I_D	7.2	A
	$T_A=70^{\circ}C$		5.7	
Power Dissipation	$T_A=25^{\circ}C$	P_D	1.7	W
	$T_A=70^{\circ}C$		1.1	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	$^{\circ}C$
Thermal Resistance ^(Note 4)	Junction to Case	$R_{\theta JC}$	13	$^{\circ}C/W$
	Junction to Ambient	$R_{\theta JA}$	75	

PJQ2568A

Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	60	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	1.5	2.1	3	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =10A	-	13	16	mΩ
		V _{GS} =4.5V, I _D =6A	-	21.4	28	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic ^(Note 6)						
Total Gate Charge	Q _g	V _{DS} =30V, I _D =10A, V _{GS} =10V ^(Note 2,3)	-	16	21	nC
Gate-Source Charge	Q _{gs}		-	3	-	
Gate-Drain Charge	Q _{gd}		-	4	-	
Input Capacitance	C _{iss}	V _{DS} =30V, V _{GS} =0V, f=1MHz	-	800	1120	pF
Output Capacitance	C _{oss}		-	273	410	
Reverse Transfer Capacitance	C _{rss}		-	28	-	
Gate resistance	R _g	f=1MHz	-	1.3	-	Ω
Turn-On Delay Time	td _(on)	V _{DS} =30V, I _D =10A, V _{GS} =10V, R _G =3Ω ^(Note 2,3)	-	6.5	-	ns
Turn-On Rise Time	tr		-	19	-	
Turn-Off Delay Time	td _(off)		-	15	-	
Turn-Off Fall Time	tf		-	15	-	
Drain-Source Diode						
Diode Forward Current	I _S	T _C =25°C	-	-	17	A
Pulsed Diode Forward Current	I _{SM}		-	-	68	
Diode Forward Voltage	V _{SD}	I _S =10A, V _{GS} =0V	-	0.85	1.3	V
Reverse Recovery Time	T _{rr}	V _{DD} =30V, V _{GS} =0V	-	16	-	ns
Reverse Recovery Charge	Q _{rr}	I _S =10A, dI _S /dt=100A/us	-	5	-	nC

NOTES :

1. Pulse width≤300us, Duty cycle≤2%.
2. Essentially independent of operating temperature typical characteristics.
3. Chip capability with an R_{θJC}=13°C/W.
4. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
5. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J=25°C.
6. Guaranteed by design, not subject to production testing.

PJQ2568A

TYPICAL CHARACTERISTIC CURVES

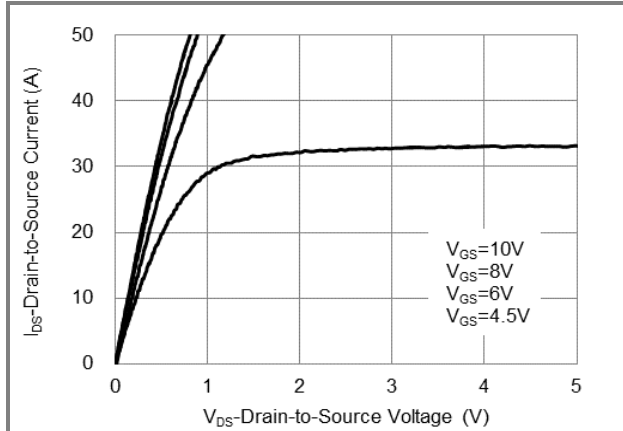


Fig.1 On-Region Characteristics

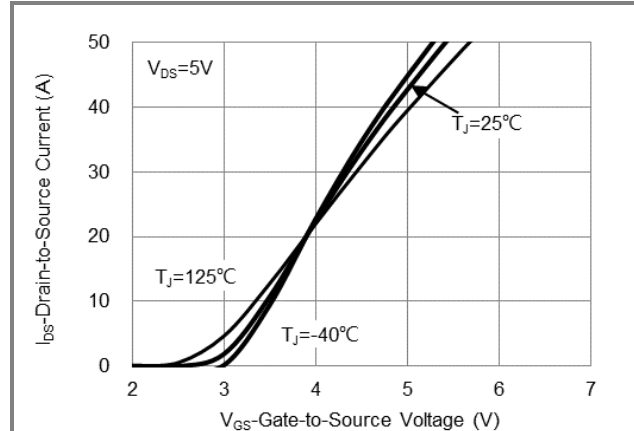


Fig.2 Transfer Characteristics

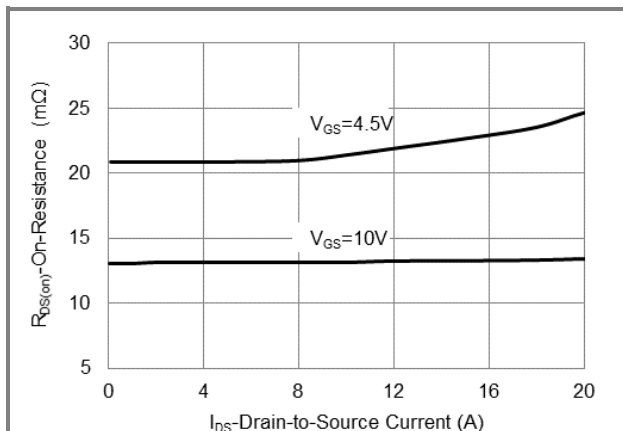


Fig.3 On-Resistance vs. Drain Current

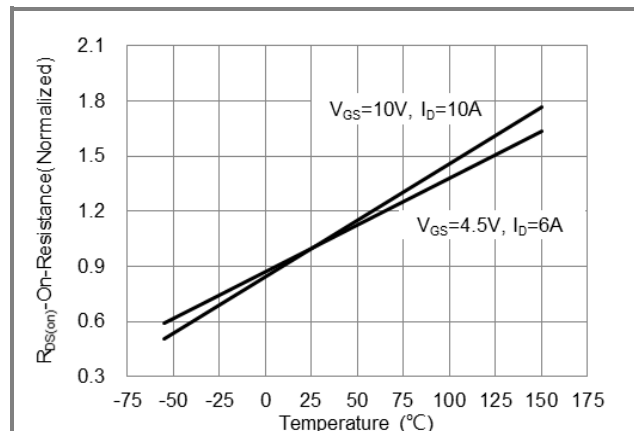


Fig.4 On-Resistance vs. Junction temperature

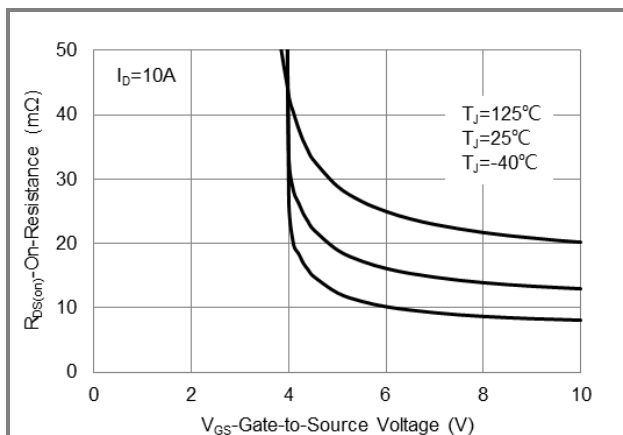


Fig.5 On-Resistance Variation with V_{GS}

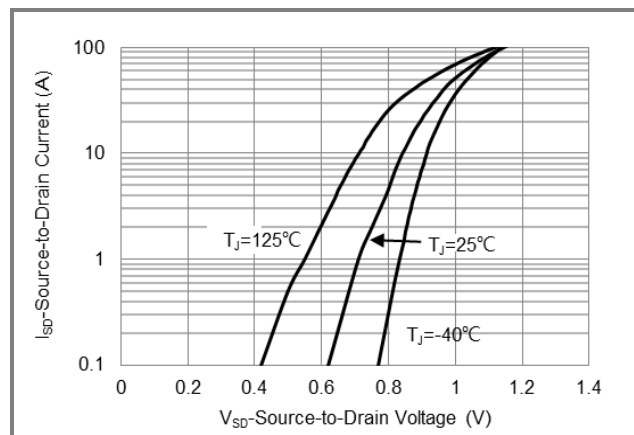
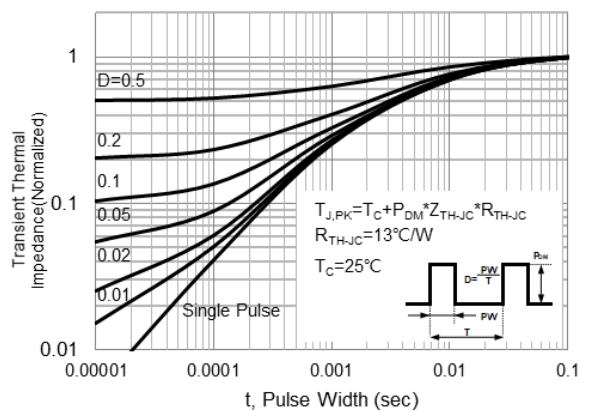
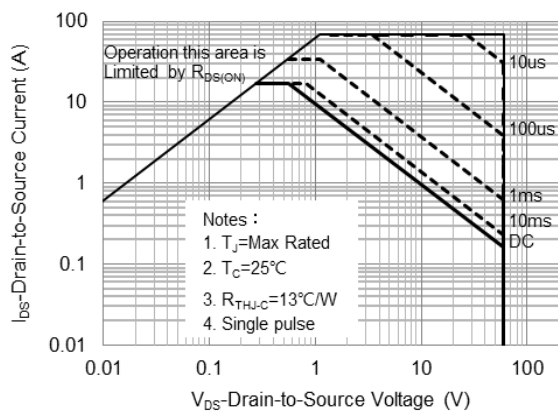
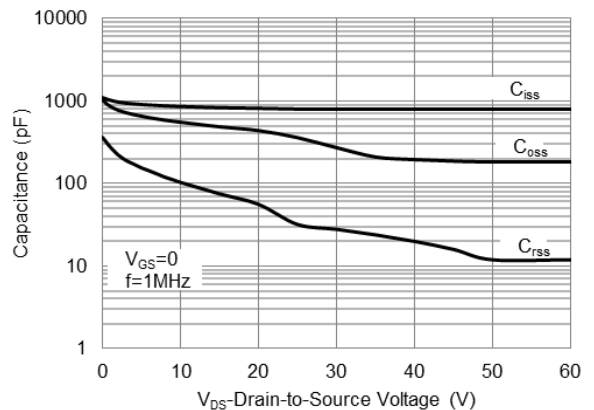
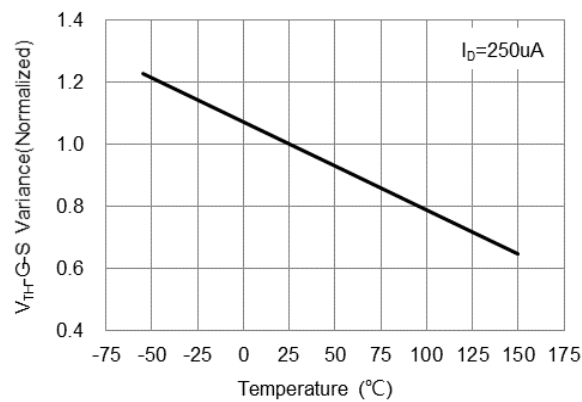
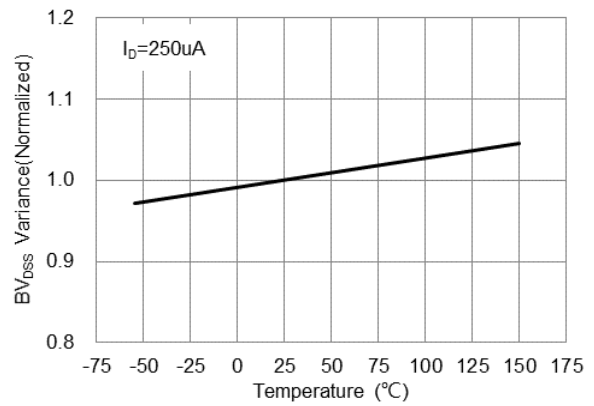
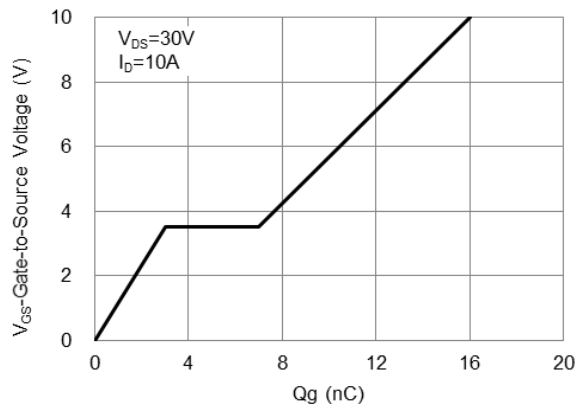


Fig.6 Source-Drain Diode Forward Voltage

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TYPICAL CHARACTERISTIC CURVES

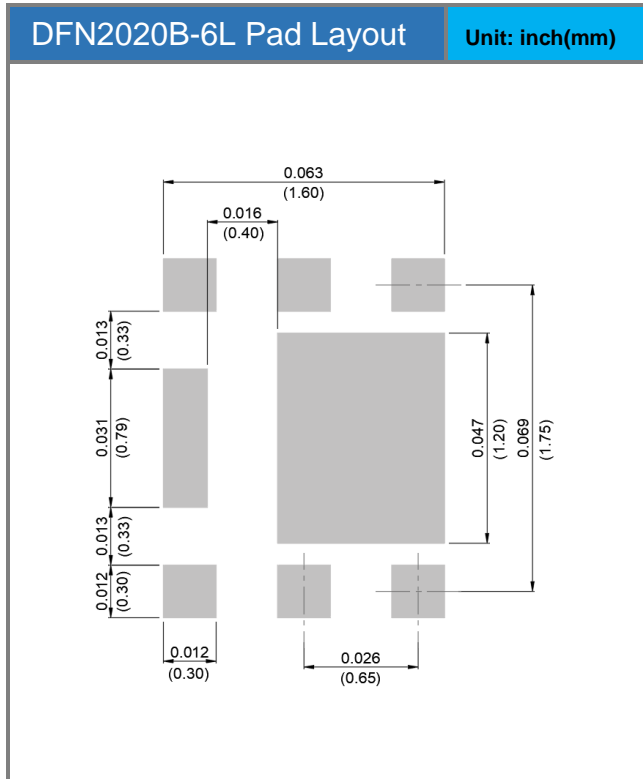
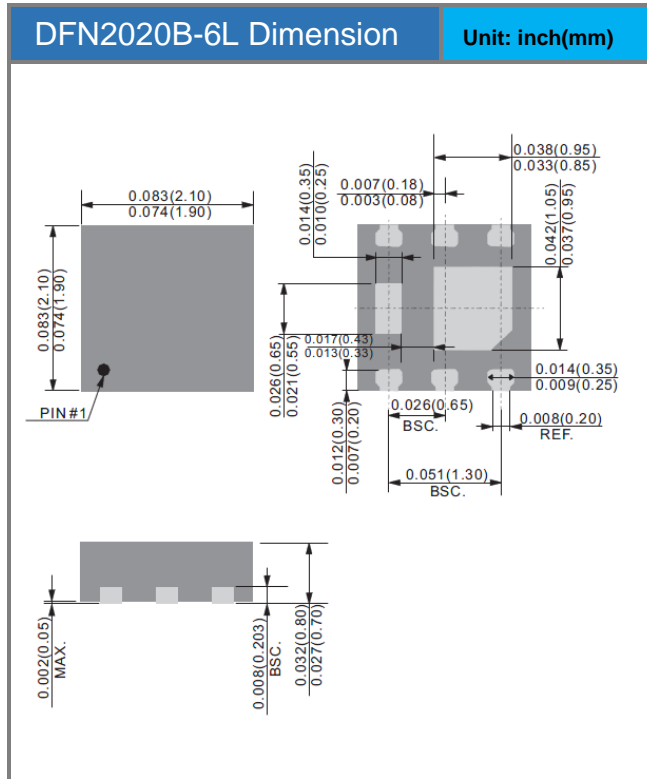


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Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJQ2568A	DFN2020B-6L	3K pcs / 7" reel	568

Packaging Information & Mounting Pad Layout



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